NSN 5961-01-505-8908

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-505-8908 **Inclosure Material:** Plastic **Overall Length:** Between 2.8 millimeters and 3.0 millimeters **Overall Height:** Between 0.9 millimeters and 1.1 millimeters **Overall Width:** Between 2.1 millimeters and 2.5 millimeters **End Application:** 4920-01-495-9100 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 85.0 repetitive peak reverse voltage and 75.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current absolute and 0.40 amperes forward current, average preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-emitter peak **Product Name:** Diode **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: